

Main Product Characteristics:

V _{DSS}	20V			
R _{DS} (on)	18mohm(typ.)			
I _D	6A			

SOT23

Features and Benefits:

Description:

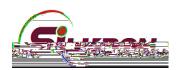
Absolute Max Rating:

Symbol	Parameter	Max.	Units		
I _D @ TC = 25°C	Continuous Drain Current, V _{GS} @ 10V	6			
I _{DM}	Pulsed Drain Current	30	A		
P _D @TC = 25°C	Power Dissipation	1.3	W		
V _{DS}	Drain-Source Voltage	20	V		
V_{GS}	Gate-to-Source Voltage	± 12	V		
ESD	ESD Rating (HBM)	2	KV		
T _J T _{STG}	Operating Junction and Storage Temperature Range	-55 to +150	°C		

Thermal Resistance

Symbol	Characterizes	Тур.	Max.	Units
R A	Junction-to-ambient (95	/W





$\textbf{Electrical Characterizes} \ @T_{A} = 25 \quad \text{ unless otherwise specified}$

Symbol	Parameter	Min.	Тур.	Max.	Units	Conditions
V _{(BR)DSS}	Drain-to-Source breakdown voltage	20			V	V _{GS}
R _{DS(on)}	Static Drain-to-Source on-resistance		18	24		V_{GS} =4.5 V , I_{D} = 6 A
			19	25		$V_{GS}=4V, I_{D}=5.5A$
			21	29		$V_{GS}=3.1V, I_{D}=5A$
			25	33		$V_{GS}=2.5V, I_{D}=4A$
$V_{GS(th)}$	Gate threshold voltage	0.5		1	V	$V_{DS} = V_{GS}, I_{D}$
I _{DSS}	Drain-to-Source leakage current			1		$V_{DS} = 20V, V_{GS} = 0V$
I _{GSS}	Gate-to-Source forward leakage			10		V _{GS} =10V
				-10		V _{GS} = -10V
g FS	Forward Transconductance		7		S	V _{DS} =5V,I _D =6A
Qg	Total gate charge		8			V _{DS} =10V,
Q _{gs}	Gate-to-Source charge		1.5		nC	I _D =6A,
Q_{gd}	Gate-to-Drain("Miller") charge		2			V _{GS} =4.5V
t _{d(on)}	Turn-on delay time		20			

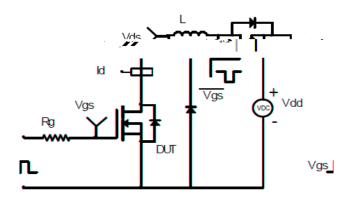
 $V_{DD}=10V,I_{D}=1A$

V_{GS}=4.5V,R_{GEN}=10

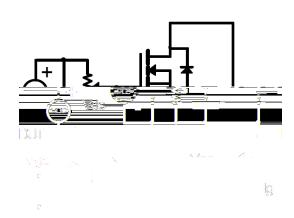


Test Circuits and Waveforms

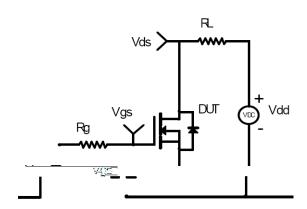
EAS Test Circuit:



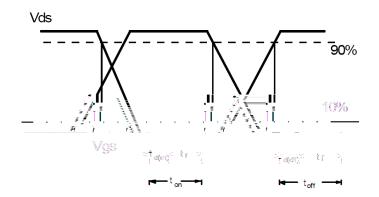
Gate Charge Test Circuit:



Switching Time Test Circuit:



Switching Waveforms:



Notes:

Calculated continuous current based on maximum allowable junction temperature.

Repetitive rating; pulse width limited by max. junction temperature.

The power dissipation PD is based on max. junction temperature, using junction-to-case thermal resistance.

The value of R $_{A}$ is measured with the device mounted on 1 in 2 FR-4 board with 2oz. Copper, in a still air environment with T_{A} =25°C





Mechanical Data

Symbol	Dimension I	n Millimeters	Dimension In Inches		
	Min	Max	Min	Max	
Α	1.050	1.250	0.041	0.049	
A1	0.000	0.100	0.000	0.004	
A2	1.050	1.150	0.041	0.045	
b	0.300	0.500	0.012	0.020	
С	0.100	0.200	0.004	0.008	
D	2.820	3.020	0.111	0.119	
Е	1.500	1.700	0.059	0.067	
E1	2.650	2.950	0.104	0.116	

e 0.95(BSC) 0.037(BSC)





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